## NSN 5961-01-185-4251

**Fiig:** A110a0

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View Online at https://aerobasegroup.com/nsn/5961-01-185-4251 **Inclosure Material:** Metal **Overall Length:** 0.645 inches **Overall Height:** 0.135 inches **Overall Width:** 0.495 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 10.00 amperes forward current, total rms horsepower metric and 100.00 amperes peak forward surge current absolute and 2.00 amperes forward current, total rms blank **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No